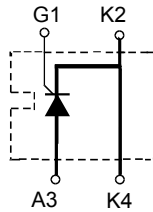
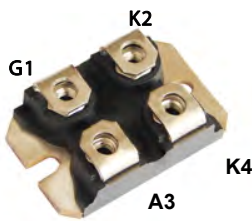
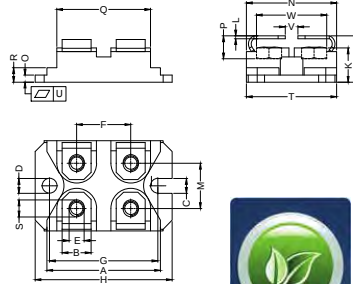


STO50GK08S

Single Thyristor Modules



Dimensions SOT-227(ISOTOP)



Dim.	Millimeter		Dim.	Millimeter	
	Min.	Max.		Min.	Max.
A	31.30	31.65	M	12.00	13.00
B	7.80	8.40	N	25.15	25.65
C	4.00	4.30	O	1.95	2.15
D	Ø4.00	Ø4.30	P	5.60	6.60
E	4.00	4.30	Q	25.30	26.30
F	14.90	15.20	R	3.90	4.30
G	30.10	30.30	S	4.45	4.85
H	38.00	38.50	T	24.50	25.10
J	12.10	12.90	U	0.05	0.10
K	9.00	9.60	V	3.00	4.80
L	0.75	0.85	W	19.30	20.50



Type	V _{RSM} V _{DSM} V	V _{RRM} V _{DRM} V
STO50GK08S	900	800

Symbol	Test Conditions		Maximum Ratings	Unit
I _{TRMS}	T _{VJ} = T _{VJM}		78	A
I _{TAVM}	T _C = 80 °C; (180°sine)		50	
I _{TSM}	T _{VJ} =45∞	t=10ms (50Hz), sine	740	A
	V _R =0	t=8.3ms (60Hz), sine	800	
	T _{VJ} =T _{VJM}	t=10ms(50Hz), sine	650	
	V _R =0	t=8.3ms(60Hz), sine	700	
I ² t	T _{VJ} =45°C	t=10ms (50Hz), sine	2740	A ² s
	V _R =0	t=8.3ms (60Hz), sine	2700	
	T _{VJ} =T _{VJM}	t=10ms(50Hz), sine	2100	
	V _R =0	t=8.3ms(60Hz), sine	2100	
(di/dt) _{cr}	T _{VJ} =T _{VJM}	repetitive, I _T =78A	150	A/us
	f=50Hz, t _p =200us V _D =2/3V _{DRM} I _G =0.3A dig/dt=0.3A/us	non repetitive, I _T =I _{TAVM}	500	
(dv/dt) _{cr}	T _{VJ} =T _{VJM} ; R _{GK} =∞; method 1 (linear voltage rise)	V _{DR} =2/3V _{DRM}	1000	V/us
P _{GM}	T _{VJ} =T _{VJM}	t _p =30us	10	W
P _{GAVM}	I _T =I _{TAVM}	t _p =300us	5	
			0.5	
V _{RGM}			10	V
T _{VJ} T _{VJM} T _{stg}			-40...+125 125 -40...+125	°C
V _{ISOL}	50/60Hz, RMS I _{ISOL} ≤1mA		2500	V~
M _d	Mounting torque (M4) Terminal connection torque (M4)		1.1-1.5/9-13 1.1-1.5/9-13	Nm/lb.in.
Weight	typical		30	g

STO50GK08S

Single Thyristor Modules

Symbol	Test Conditions	Characteristic Values	Unit
I_R, I_D	$T_{VJ}=T_{VJM}; V_R=V_{RRM}; V_D=V_{DRM}$	≤ 3	mA
V_T	$I_T=50A; T_{VJ}=25^{\circ}C$	≤ 1.30	V
V_{TO}	For power-loss calculations only	≤ 0.90	V
r_T		≤ 5.8	m Ω
V_{GT}	$V_D=6V; T_{VJ}=25^{\circ}C$ $T_{VJ}=-40^{\circ}C$	≤ 1.4 ≤ 1.6	V
I_{GT}	$V_D=6V; T_{VJ}=25^{\circ}C$ $T_{VJ}=-40^{\circ}C$	≤ 100 ≤ 150	mA
V_{GD}	$T_{VJ}=T_{VJM}; V_D=2/3V_{DRM}$	≤ 0.2	V
I_{GD}		≤ 5	mA
I_L	$T_{VJ}=25^{\circ}C; t_p=10\mu s$ $I_G=0.3A; di_G/dt=0.3A/\mu s$	≤ 450	
I_H	$T_{VJ}=25^{\circ}C; V_D=6V; R_{GK}=\infty$	≤ 200	
t_{gd}	$T_{VJ}=25^{\circ}C; V_D=1/2V_{DRM}$ $I_G=0.3A; di_G/dt=0.3A/\mu s$	≤ 2	μs
t_q	$T_{VJ}=T_{VJM}; I_T=20A; t_p=200\mu s; di/dt=-10A/\mu s$ typ. $V_R=100V; dv/dt=15V/\mu s; V_D=2/3V_{DRM}$	≤ 150	
R_{thJC}	DC current	≤ 0.72	K/W
R_{thCH}	DC current	≤ 0.40	
d_s	Creeping distance on surface	≤ 8	mm
d_A	Creepage distance in air	≤ 4	
a	Max. allowable acceleration	≤ 50	m/s ²

FEATURES

- *Thyristor controller for AC for mains frequency
- *International standard package SOT-227B(ISOTOP compatible)
- *Isolation voltage 2500V~
- *Glass passivated chips
- *UL File NO. E310749
- *RoHS compliant

APPLICATIONS

- *Switching and control of single and three phase AC Softstart
- *AC motor controller
- *Solid states witches
- *Light and temperature control

ADVANTAGES

- *Easy to mount with two screws
- *Space and weight savings
- *Improved temperature and power cycling
- *High power density